TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA48018F,TA4802F,TA48025F,TA4803F,TA48033F,TA4805F, TA48018S,TA4802S,TA48025S,TA4803S,TA48033S,TA4805S

1.8 V, 2 V, 2.5 V, 3 V, 3.3 V, 5 V

Three-Terminal Low Dropout Voltage Regulator with Output Current of 1 A

The TA48**F/S series consists of fixed-positive-output, low-dropout regulators and V-PNP transistors for output stage with an output current of 1 A (max). In response to the need for low-voltage and low-power dissipation devices which are used in consumer electronics and industrial appliances, the series offers devices with low output voltages: 1.8 V, 2 V, 2.5 V, 3 V, 3.3 V, 5 V.

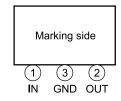
Features

- Maximum output current: 1 A •
- Output voltage accuracy: $V_{OUT} \pm 3\%$ (@T_i = 25°C)
- Low standby current: 800 µA (typ.) (@IOUT = 0 A)
- Low starting quiescent current
- Low-dropout voltage: $V_D = 0.5 V (max) (@I_{OUT} = 0.5 A)$
- Protection function: overheat/overcurrent
- Package type: PW-MOLD (TA48**F Series)

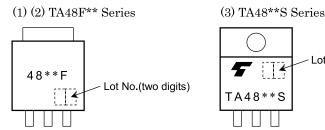
TO-220NIS (TA48**S Series)

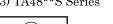
• TA48**F Series has the lead bending type package which is the surface-mount package and can be used for reflow soldering (surface mountable).

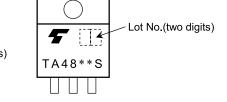
Pin Assignment

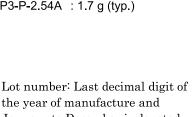


Marking



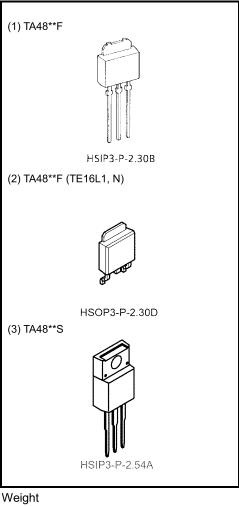






January to December is denoted by letter A to L respectively.

Note: The "**" in the each product number is replaces with the output voltage of each product.

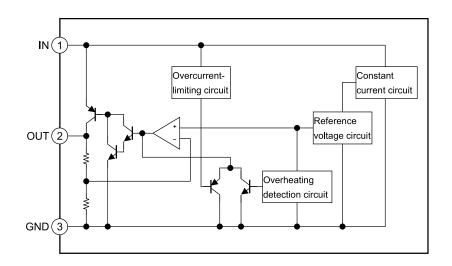


HSIP3-P-2.30B : 0.36 g (typ.) HSOP3-P-2.30D: 0.36 g (typ.) HSIP3-P-2.54A : 1.7 g (typ.)

How to Order

	Product No.	Package	Packing Type and Unit for Orders
(1)	TA48**F	PW-MOLD: Straight-lead package	Loose in bag: 200 (1 bag)
(2)	TA48**F (TE16L1, N)	PW-MOLD: Surface-mount package	Embossed-tape packing: 2000 (1 tape)
(3)	TA48**S	TO-220NIS	Loose in bag: 50 (1 bag)

Block Diagram



Maximum Ratings (Ta = 25°C)

Characteris	tic	Symbol	Rating	Unit
Input voltage	put voltage		16	V
Output current		lout	1	А
Operating temperature		Ta _(opr)	-40~85	°C
Junction temperature		Тј	150	°C
Storage temperature		T _{stg}	-55~150	°C
Power dissipation	TA48**F	D-	1	W
(Ta = 25°C)	TA48**S	P _D	2	vv
Power dissipation	TA48**F	PD	10	W
(Tc = 25°C)	TA48**S	гD	20	vv
Thermal resistance	TA48**F	D	125	°C/W
(junction to ambient)	TA48**S	P _{th (j-a)}	62.5	C/W
Thermal resistance	TA48**F	Denne	12.5	°C/W
(junction to case)	TA48**S	P _{th (j-c)}	6.25	C/VV

Note 1: Must not to apply external current and voltage (including negative voltage) to not specified pins.

Protection Function (reference)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Thermal shutdown	T _{SD} (T _j)	—	_	160	_	°C
Peak circuit current		V _{IN} = V _{OUT} + 2 V, T _j = 25°C	— 1.7	1.7		A
Peak circuit current	PEAK	V _{IN} = 12 V, T _j = 25°C		1.8	-	
Short circuit current		V _{IN} = V _{OUT} + 2 V, T _j = 25°C		1.7		A
	ISC	V _{IN} = 12 V, T _j = 25°C		1.8	-	

Note 2: When the IC is actually used, must not exceed maximum ratings.

TA48018F/S Electrical Characteristics (C_{IN} = 0.33 μ F, C_{OUT} = 10 μ F, T_j = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 3.8 V, I _{OUT} = 0.5 A	1.746	1.8	1.854	v
Output voltage	V _{OUT}	$\begin{array}{l} 2.8 \ V \leqq V_{IN} \leqq 12 \ V, \ 5 \ mA \leqq I_{OUT} \leqq 1 \ A, \\ 0^{\circ}C \leqq T_{j} \leqq 125^{\circ}C \end{array}$	1.72	1.8	1.88	
Line regulation	Reg∙line	2.8 V \leq V $_{IN}$ \leq 12 V, I_{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 3.8 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current		2.8 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A	_	0.8	1.8	mA
Quescent current	B	2.8 V \leq V _{IN} \leq 12 V, I _{OUT} = 1 A	_	10	20	
Starting quippoont ourrant	Bstart	V _{IN} = 2.1 V, I _{OUT} = 0 A	_	0.7	5	mA
Starting quiescent current		V _{IN} = 2.5 V, I _{OUT} = 1 A	_	10	30	
Output noise voltage	V _{NO}	V _{IN} = 3.8 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	75	_	μVrms
Ripple rejection	R.R.	2.8 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	54	70	_	dB
Drenout voltage	N/-	I _{OUT} = 0.5 A	_	0.3	0.5	v
Dropout voltage	VD	I _{OUT} = 1 A	_	0.7	_	
Average temperature coefficient of output voltage	T _{CVO}	V_{IN} = 3.8 V, I_{OUT} = 5 mA, 0°C \leq T _j \leq 125°C	_	0.15		mV/°C

TA4802F/S Electrical Characteristics ($C_{IN} = 0.33 \ \mu$ F, $C_{OUT} = 10 \ \mu$ F, $T_j = 25^{\circ}$ C, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 4.0 V, I _{OUT} = 0.5 A	1.94	2.0	2.06	v
Output voltage	V _{OUT}	$\begin{array}{l} 3.0 \ V \leqq V_{IN} \leqq 12 \ V, \ 5 \ mA \leqq I_{OUT} \leqq 1 \ A, \\ 0^{\circ}C \leqq T_{j} \leqq 125^{\circ}C \end{array}$	1.91	2.0	2.09	
Line regulation	Reg∙line	3.0 V \leq V $_{IN}$ \leq 12 V, I_{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 4.0 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current	I _	3.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A	_	0.8	1.8	mA
	Ι _Β	3.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 1 A	_	10	20	
Starting quiescent current		V _{IN} = 2.1 V, I _{OUT} = 0 A	_	0.7	5	mA
Starting quiescent current	Bstart	V _{IN} = 2.6 V, I _{OUT} = 1 A	_	10	5 30	
Output noise voltage	V _{NO}	V _{IN} = 4.0 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	80	_	μVrms
Ripple rejection	R.R.	3.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	52	68	_	dB
Dropout voltage)/-	I _{OUT} = 0.5 A	_	0.3	0.5	v
Dropout voltage	VD	I _{OUT} = 1 A	_	0.6	_	V
Average temperature coefficient of output voltage	T _{CVO}	V_{IN} = 4.0 V, I_{OUT} = 5 mA, 0°C \leq T _j \leq 125°C	_	0.18	_	mV/°C

TA48025F/S Electrical Characteristics (C_{IN} = 0.33 μ F, C_{OUT} = 10 μ F, T_j = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 4.5 V, I _{OUT} = 0.5 A	2.425	2.5	2.575	v
Output voltage	V _{OUT}	$\begin{array}{l} 3.5 \ V \leqq V_{IN} \leqq 12 \ V, \ 5 \ mA \leqq I_{OUT} \leqq 1 \ A, \\ 0^{\circ}C \leqq T_{j} \leqq 125^{\circ}C \end{array}$	2.388	2.5	2.612	
Line regulation	Reg∙line	3.5 V \leq V _{IN} \leq 12 V, I _{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 4.5 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current	I_	3.5 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A		0.8	1.8	mA
	B	$3.5 \text{ V} \leq \text{V}_{IN} \leq 12 \text{ V}, \text{ I}_{OUT} = 1 \text{ A}$		10	20	ША
Starting guiageant ourrant		V _{IN} = 2.1 V, I _{OUT} = 0 A		0.9	5	- mA
Starting quiescent current	Bstart	V _{IN} = 2.65 V, I _{OUT} = 1 A	_	12	30	
Output noise voltage	V _{NO}	V _{IN} = 4.5 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	95	_	μVrms
Ripple rejection	R.R.	3.5 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	52	68	_	dB
Dranaut voltage	\/-	I _{OUT} = 0.5 A		0.3	0.5	v
Dropout voltage	VD	I _{OUT} = 1 A		0.4		
Average temperature coefficient of output voltage	T _{CVO}	V_{IN} = 4.5 V, I_{OUT} = 5 mA, 0°C \leq T _j \leq 125°C		0.24	_	mV/°C

TA4803F/S Electrical Characteristics ($C_{IN} = 0.33 \ \mu$ F, $C_{OUT} = 10 \ \mu$ F, $T_j = 25^{\circ}$ C, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 5.0 V, I _{OUT} = 0.5 A	2.91	3.0	3.09	v
Output voltage	V _{OUT}	$\begin{array}{l} 4.0 \; V \leqq V_{IN} \leqq 12 \; V, \; 5 \; mA \leqq I_{OUT} \leqq 1 \; A, \\ 0^{\circ}C \leqq T_{j} \leqq 125^{\circ}C \end{array}$	2.865	3.0	3.135	
Line regulation	Reg∙line	4.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 5.0 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current	I_	4.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A	_	0.8	1.8	mA
	Ι _Β	4.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 1 A	_	10	20	
Starting guioscopt current		V _{IN} = 2.1 V, I _{OUT} = 0 A	_	1.1	5	mA
Starting quiescent current	Bstart	V _{IN} = 2.8 V, I _{OUT} = 1 A	_	13	5 30	
Output noise voltage	V _{NO}	V _{IN} = 5.0 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	110	_	μVrms
Ripple rejection	R.R.	4.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	50	66	_	dB
Dropout voltage	\/-	I _{OUT} = 0.5 A	_	0.3	0.5	v
Dropout voltage	VD	I _{OUT} = 1 A	_	0.4	_	
Average temperature coefficient of output voltage	T _{CVO}	V _{IN} = 5.0 V, I _{OUT} = 5 mA, 0°C ≦ T _j ≦ 125°C	_	0.28	_	mV/°C

TA48033F/S Electrical Characteristics (C_{IN} = 0.33 μ F, C_{OUT} = 10 μ F, T_j = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 5.3 V, I _{OUT} = 0.5 A	3.2	3.3	3.4	
Output voltage	V _{OUT}	$\begin{array}{l} 4.3 \ V \leq V_{IN} \leq 12 \ V, \ 5 \ mA \leq I_{OUT} \leq 1 \ A, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C \end{array}$	3.152	3.3	3.448	
Line regulation	Reg∙line	4.3 V \leq V _{IN} \leq 12 V, I _{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 5.3 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current	I_	4.3 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A	_	0.8	1.8	mA
	B	4.3 V \leq V _{IN} \leq 12 V, I _{OUT} = 1 A	_	10	20	IIIA
Starting guiageant ourrant		V _{IN} = 2.1 V, I _{OUT} = 0 A	_	1.1	5	m 4
Starting quiescent current	Bstart	V _{IN} = 2.8 V, I _{OUT} = 1 A	_	13	30	mA
Output noise voltage	V _{NO}	V _{IN} = 5.3 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	115	_	μVrms
Ripple rejection	R.R.	4.3 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	50	66	_	dB
Dranaut voltage		I _{OUT} = 0.5 A	_	0.3	0.5	v
Dropout voltage	VD	I _{OUT} = 1 A	_	0.4	_	v
Average temperature coefficient of output voltage	T _{CVO}	V_{IN} = 5.3 V, I_{OUT} = 5 mA, 0°C \leq T _j \leq 125°C	_	0.3	_	mV/°C

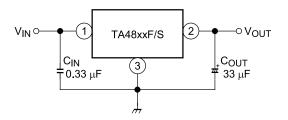
TA4805F/S Electrical Characteristics ($C_{IN} = 0.33 \ \mu\text{F}, C_{OUT} = 10 \ \mu\text{F}, T_i = 25^{\circ}\text{C}$, unless otherwise specified)

Characteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
		V _{IN} = 7 V, I _{OUT} = 0.5 A	4.85	5.0	5.15	v
Output voltage	V _{OUT}	$\begin{array}{l} \textbf{6.0 V} \leq \textbf{V}_{IN} \leq \textbf{12 V}, \textbf{5 mA} \leq \textbf{I}_{OUT} \leq \textbf{1 A}, \\ \textbf{0^{\circ}C} \leq \textbf{T}_{j} \leq \textbf{125^{\circ}C} \end{array}$	4.775	5.0	5.225	
Line regulation	Reg∙line	6.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 0.5 A	_	5	20	mV
Load regulation	Reg∙load	V_{IN} = 7.0 V, 5 mA $\leq I_{OUT} \leq$ 1 A	_	5	20	mV
Quiescent current	L	6.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 0 A	_	0.8	1.8	mA
	B	6.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 1 A	_	10	20	
Starting autopaget current		V _{IN} = 2.1 V, I _{OUT} = 0 A	_	1.3	5	- mA
Starting quiescent current	Bstart	V _{IN} = 3.0 V, I _{OUT} = 1 A		14		
Output noise voltage	V _{NO}	V _{IN} = 7.0 V, I _{OUT} = 50 mA 10 Hz ≦ f ≦ 100 kHz	_	150	_	μVrms
Ripple rejection	R.R.	6.0 V \leq V _{IN} \leq 12 V, I _{OUT} = 50 mA f = 120 Hz	50	64	_	dB
Dropout voltage	\/-	I _{OUT} = 0.5 A	_	0.3	0.5	V
Dropout voltage	VD	I _{OUT} = 1 A	_	0.4	_	V
Average temperature coefficient of output voltage	T _{CVO}	V_{IN} = 7.0 V, I_{OUT} = 5 mA, 0°C \leq T _j \leq 125°C	_	0.45	_	mV/°C

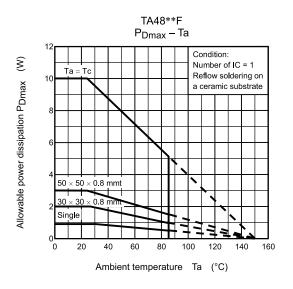
Electrical Characteristics for All Products

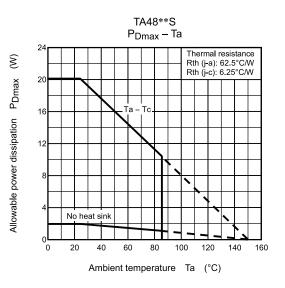
Generally, the characteristics of power supply ICs change according to temperature fluctuations. The specification $T_j = 25^{\circ}C$ is based on a state where temperature increase has no effect (assuming no fluctuation in the characteristics) as ascertained by pulse tests.

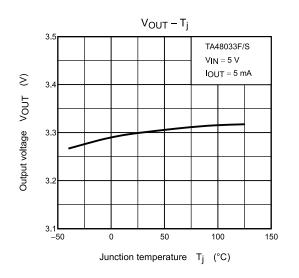
Standard Application Circuit

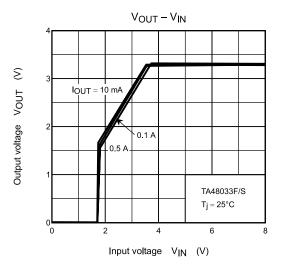


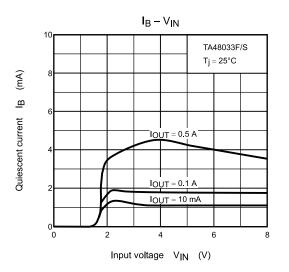
Connect the input terminal and GND, and the output terminal and GND, by capacitor respectively. The capacitances should be determined experimentally. In particular, adequate investigation should be made so that there is no problem even at time of high or low temperature.

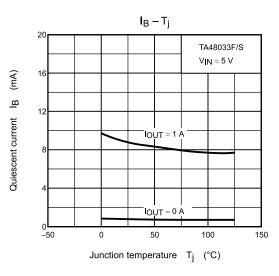




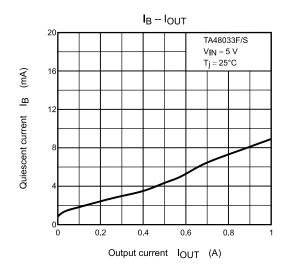


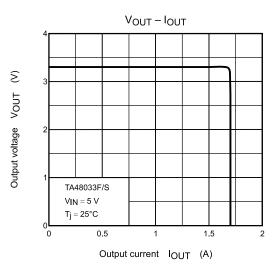


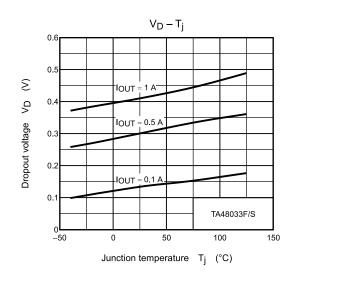


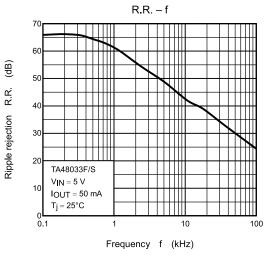


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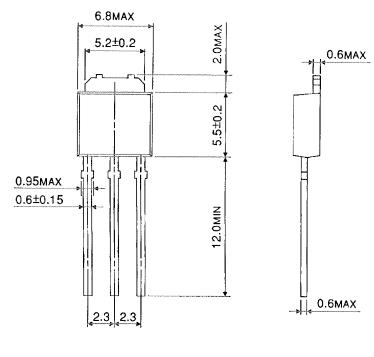


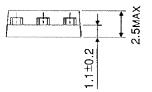




Package Dimensions

HSIP3-P-2.30B





Weight: 0.36 g (typ.)

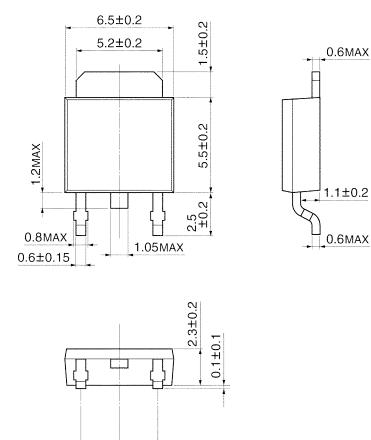
Unit : mm

TOSHIBA

Package Dimensions

HSOP3-P-2.30D

Unit: mm



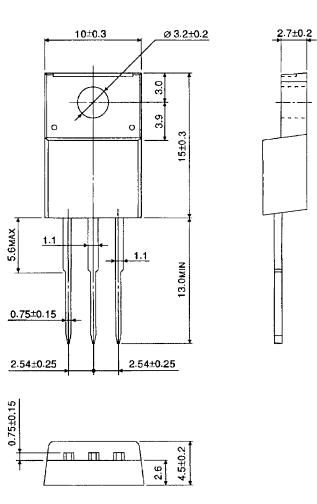
2.3±0.15 2.3±0.15

Weight: 0.36 g (typ.)

TOSHIBA

Package Dimensions

HSIP3-P-2.54A



Weight: 1.7 g (typ.)

Unit: mm

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 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
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